Introductions

Invented by Binnig and Rohrer at IBM in 1981/12 Drice innthrow 1986). 1

Binning also invented the Atomic Force Microscope(AFa) at Stanford University in 1986.

First instrument to give 3

Dimages of solid surface 1 with atomic resolution.

Formation of nanofeauters by localised heating or / inducing chemical reactions.

Marginification 10

3

in x, y, and z directions (
with high resolution

Theory and Principle

STM employs principle of electron tunneling.

The quantum mechanical equation assign a non zero probability for a on 6 to tunnel through the barrier even if its energy is less than the patention of 1 barrier!

Two metals must be separated by a space of not more than 10nm.

Tunneling current decreases exponentially with separation between tip and sample...

Experimental methods

the 1 sample

you want to study o

a sharp metal /

mounted on a O piezoelectric crystal tube to be e placed in very close proximity to u the sample 1

a mechanism to control the location. of the tip in the x

> y plane parallel to, the sample surface 1

> > \bigcirc

feedback

loop to control the u height of the tip above the sample u

aris) C

Basic Sel

How to operate?

Raster

tip

across

the surface

 $q\chi$

0

distance

0

3 -

While the

current

between

the

and

sample surface

`S

measured

And

using the

current

20

0

feedback

moves

over

the

sample

with

its

height

being

adjusted

continuously

to

keep

tunneling

current

constant

Tip
position

monitored

to

map

the

surface

topography

the Sample

Tip

tungsten or PtIr alloy is used.

Tip movement in 3

D is controlled by piezelectric arrays.

Spatial resolution is 0.01nm in x and y directions. And about 1 0.002nm in 2

direction giving a true atomic resolution image e in 3

 \mathcal{D}

Modes of Operation

Constant current

Constant current is maintained between tip and sample.

Vertical position of the tip is changed to mountain a constaint currer between the two.

Advantages

Provides excellent surface topographic contrast of the surface atom?

Disadvantage

Slower scan rate.

Constant height mode

Distance between tiprogal sample is kept constant.

Constant tip position results in variations in tunneling current.

Advantage

faster scan rate possible

Imaging the structure of electrode surface

 \bigcirc

STIM images of the hu(M1) relectrate care

Concluding remarks

Disadvantage of STM.

. 1

Making atomically sharp tips remains something of a darkarte

2.

Etternal and internal vibrations from fans, pumps, machinery, building r movements, etc. are big problems. 3 UHV

STM is not easy to built and u handle

4.

he STM can only scan conductive surfaces or thin nonconductive films are small objects deposited on conductive substrates. It does not work with nonconductive materials, such as glass, rock, etc.

The spatial resolution of STM is fantastic, but the tenpantarous typically on the order of seconds, which prevents STM-from imaging fast a knetics of electrochemical process."

STM is one the most powerful imaging tools with an unprecedented precision.